

7 W Pulsed High Power Amplifier 2.7 - 3.0 GHz, 6 mm PQFN 28-LD

Rev. V3

Features

- 7 W Pulsed Output Power (Saturated)
- 23 dB Gain
- +10 V Bias Operation
- 50 Ω Impedance, Balanced Design
- Lead-Free 6 mm 28-lead PQFN Package
- Halogen-Free “Green” Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MAAP-011022 is a 2.7 to 3.0 GHz high power balanced amplifier, which is designed for S-Band aviation and weather radar applications. This device puts out 7 W pulsed and is designed to operate at an 8% duty cycle.

The MAAP-011022 is packaged in a lead-free 6 mm 28-lead plastic package for high volume manufacturing. This IC utilizes one of MACOM's advanced 0.5 μ m processes, which has been optimized so amplifiers, passives, and control components can be combined on a single IC.

This MAAP-011022 is specifically targeted for avionics and weather radar.

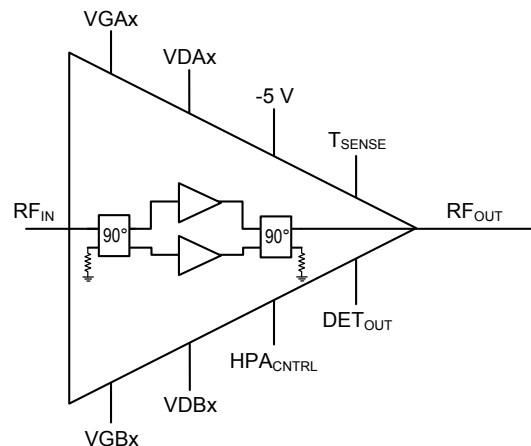
Ordering Information^{1,2}

Part Number	Package
MAAP-011022-TR0500	500 piece reel
MAAP-011022-001SMB	Sample Test Board

1. Reference Application Note M513 for reel size information.
2. Sample board includes 5 loose parts.

*Restrictions on Hazardous Substances,
European Union Directive 2011/65/EU.

Functional Block Diagram



Pin Configuration^{3,4,5,6}

Pin No.	Function	Pin No.	Function
1	VD2A	15	VC_OUT
2	No Connection	16	VG1B
3	VD1A	17	VG2B
4	No Connection	18	No Connection
5	VG2A	19	VD1B
6	VG1A	20	No Connection
7	No Connection	21	VD2B
8	No Connection	22	No Connection
9	RF_IN	23	RF_OUT
10	No Connection	24	No Connection
11	No Connection	25	No Connection
12	No Connection	26	No Connection
13	HPA_CNTRL	27	DET_OUT
14	-5 V	28	T_SENSE
		29 ⁷	Ground Pad

3. See the evaluation board schematic for the recommended external components.
4. VDAx and VDBx are connected to the +10 V bias.
5. The gates are controlled internally from the bias circuit shown on the evaluation board schematic but need to be bypassed as shown. VGAX must be connected to VGBx.
6. HPA_CNTRL is tied to +5 V for drain switching. For gate switching the PA is turned off when HPA_CNTRL is at 0 V.
7. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

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Electrical Specifications: Freq. = 2.7 - 3.0 GHz, $T_A = 25^\circ\text{C}$, $V_{DAx} = V_{DBx} = +10\text{ V}$, $I_{DQ} = \sim 2.0\text{ A}$, $Z_0 = 50\ \Omega$, 80 μs Pulse, 8% Duty Cycle

Parameter	Units	Min.	Typ.	Max.
Small-Signal Gain	dB	21.0	23.5	25
Input / Output Return Loss	dB	-	20	-
P1dB	dBm		37.5	-
P_{SAT} ($P_{IN} = +18\text{ dBm}$)	dBm	37.0	38.3	-
PAE	%	-	28.0	-
Power Detector Voltage ⁸ @ P3dB	mV	-	2200	-
Temperature Sensor Voltage ⁹ @ 25°C	V	-3.50	-3.24	-3.00
-5 V Current	mA	-	9.0	20.0
Drain Current	A	-	2.5	3.4

8. Under RF drive.

9. Slope $-1.69\text{ mV}/^\circ\text{C}$
Absolute Maximum Ratings^{10,11,12,13}

Parameter	Absolute Maximum
RF Input Power	+25 dBm
Drain Voltage	12 V
Gate Voltage (V_{GAx} , V_{GBx})	-3 V to 0 V ¹³
Negative Voltage	-6 V $\leq$ -5 V Bias $\leq$ 0.5 V
Duty Cycle	10 %
Operating Temperature	-40°C to $+85^\circ\text{C}$
Junction Temperature ¹⁴	160°C
Storage Temperature	-65°C to $+125^\circ\text{C}$

10. Exceeding any one or combination of these limits may cause permanent damage to this device.

11. MACOM does not recommend sustained operation near these survivability limits.

12. Operating at nominal conditions with $T_J \leq 160^\circ\text{C}$ will ensure MTTF $> 1 \times 10^6$ hours.13. V_{GAx} , V_{GBx} can go to +0.3 V if no drain voltage is applied.14. Junction Temperature (T_J) = $T_C + \Theta_{JC} * ((V * I) - (P_{OUT} - P_{IN}))$

Typical thermal resistance:

80 μs pulse, 8% duty cycle, $\Theta_{JC} = 2.0^\circ\text{C}/\text{W}$ a) For $T_C = +25^\circ\text{C}$, $T_J = 62^\circ\text{C}$ @ 10 V, 2.5 A, $P_{OUT} = 6.6\text{ W}$, $P_{IN} = 0.07\text{ W}$ b) For $T_C = +85^\circ\text{C}$, $T_J = 143^\circ\text{C}$ @ 10 V, 3.4 A, $P_{OUT} = 5.0\text{ W}$, $P_{IN} = 0.07\text{ W}$
Handling Procedures

Please observe the following precautions to avoid damage:

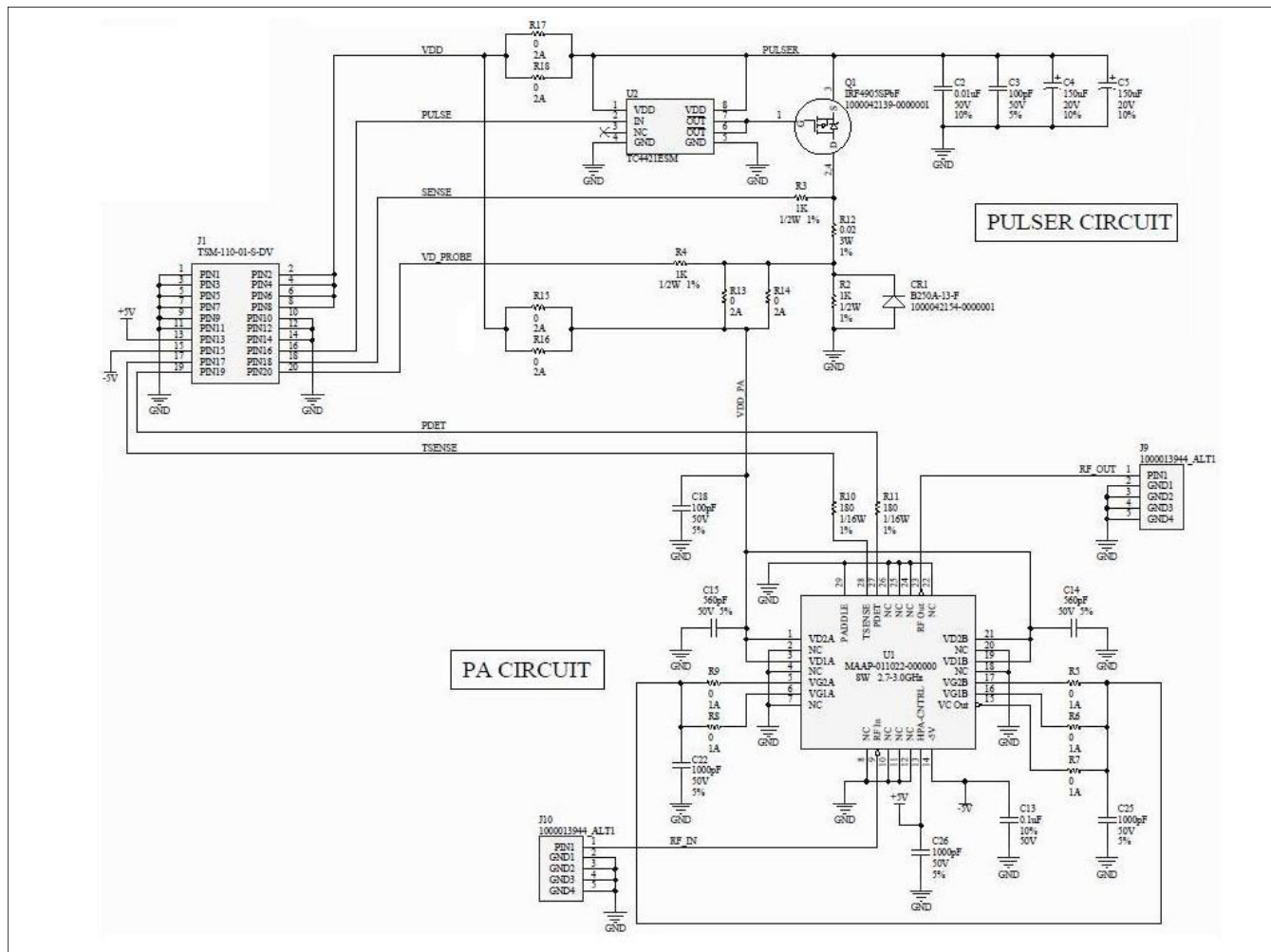
Static Sensitivity

Gallium Arsenide and Silicon Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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Evaluation Board Schematic^{15,16}



15. The standard build configuration is to omit resistors R15 & R16. This configuration activates the on-board +10 V pulser circuit.
16. In order to bypass on-board +10 V pulser circuit, remove R13, R14, R17 & R18, and add R15 & R16.

Parts List

Part	Value	Case Style
CR1	50 V Diode	-
C2	.01 μ F	0603
C3, C18	100 pF	0603
C4, C5	150 μ F	-
C13	0.1 μ F	0402
C14, C15	560 pF	0402
C22, C25	1000 pF	0402
R1, R5 - R9	0 Ω	0402
R2 - R4	1 k Ω	1210
R10, R11	180 Ω	0402
R12	0.02 Ω	4527
R13 - R18	0 Ω	1206

Parts List

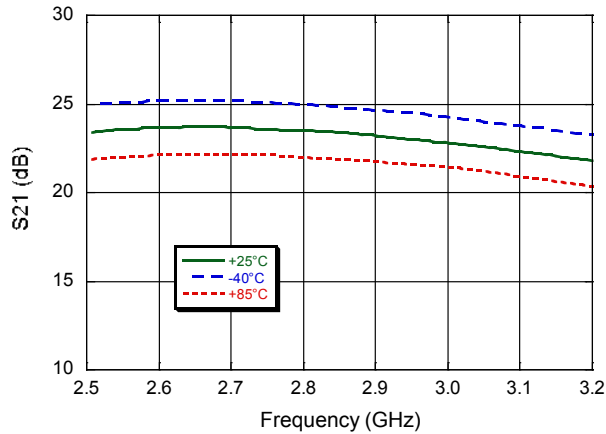
Part	Value	Case Style
J1	10 Row	Header
J7 - J10	Connector	SMA
Q1	IRF4905SPbF	T0-220AB
U1	8 W HPA	6mm PQFN-28LD
U2	TC4421ESM	8-SOIC

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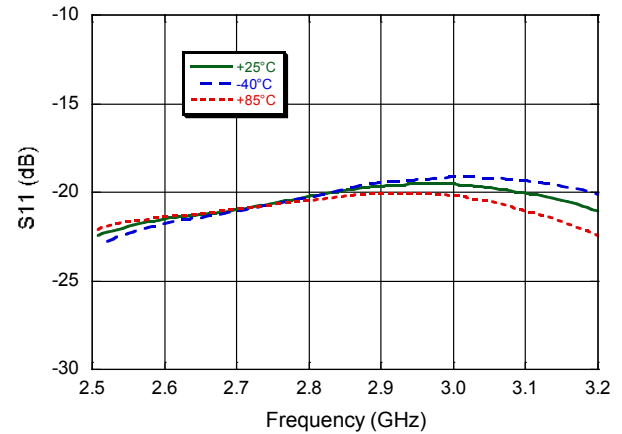
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Typical Performance Curves: $V_{DAx}=V_{DBx}=10\text{ V}$, $I_{DQ}=2.0\text{ A}$ (80 μs Pulse, 8% Duty Cycle)

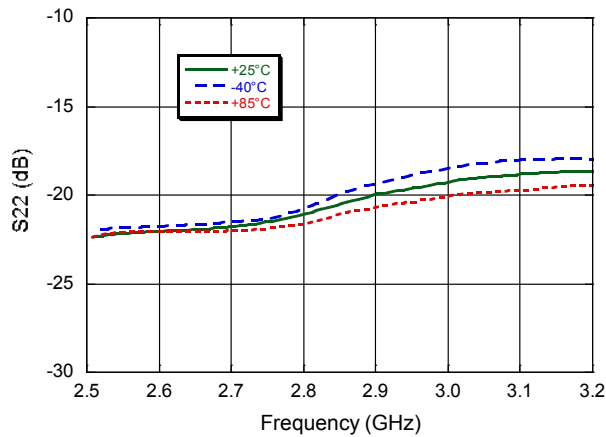
Gain vs. Frequency



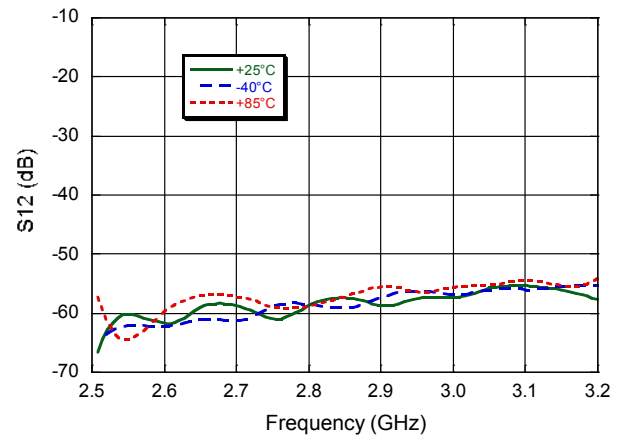
Input Return Loss vs. Frequency



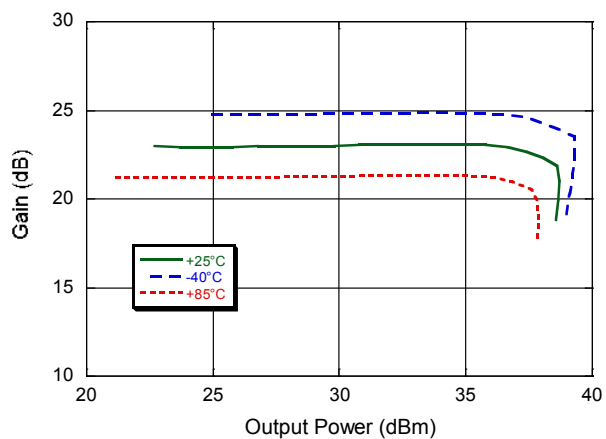
Output Return Loss vs. Frequency



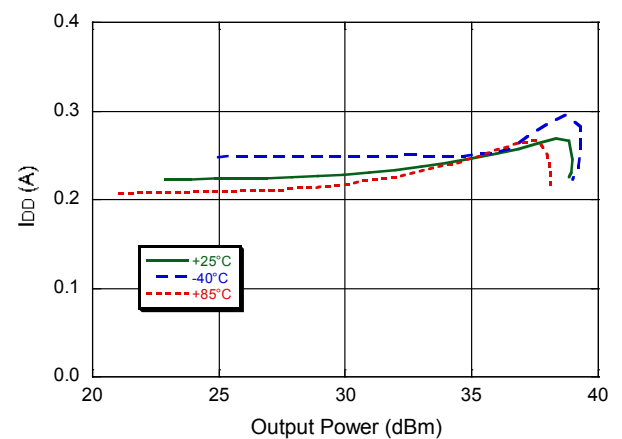
Reverse Isolation vs. Frequency



Gain vs. Output Power



Drain Current vs. Output Power
(80 μs Pulse, 8% Duty Cycle)

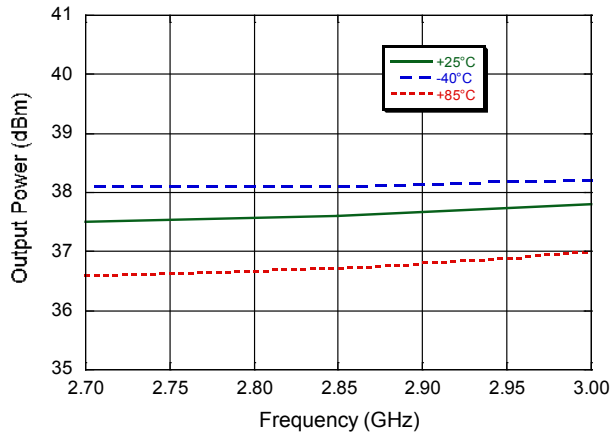


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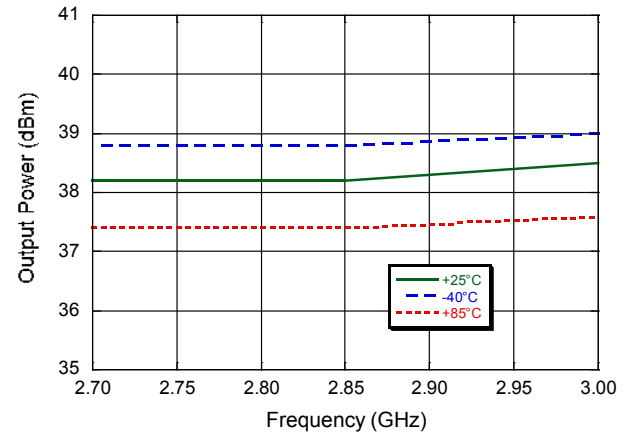
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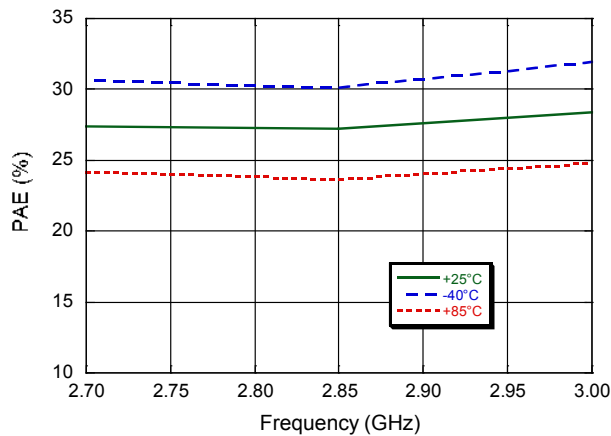
P1dB vs. Frequency



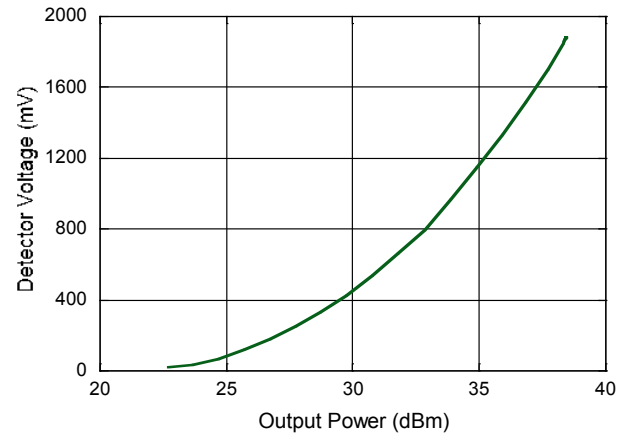
P3dB vs. Frequency



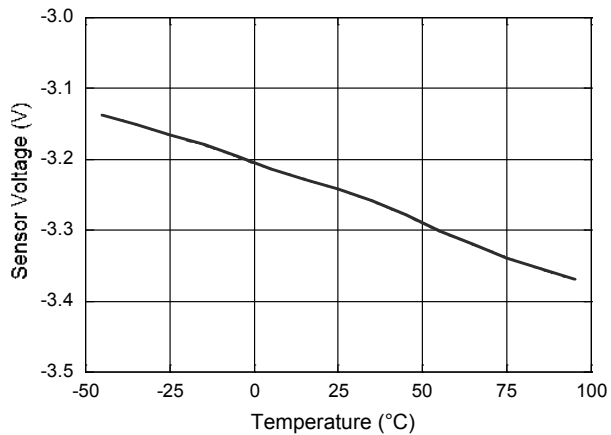
PAE vs. Frequency



Power Detector Voltage vs. Output Power



Temperature Sensor Voltage vs. Temperature

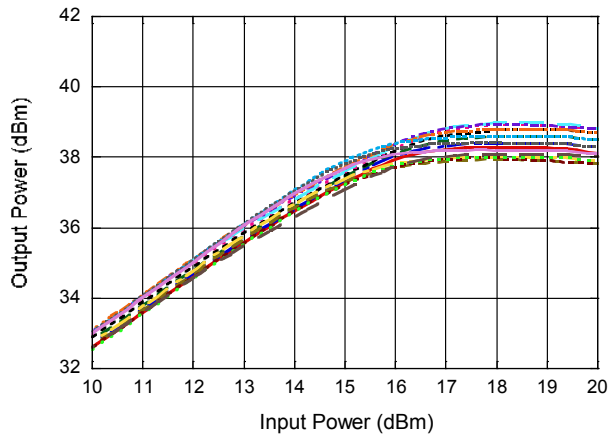


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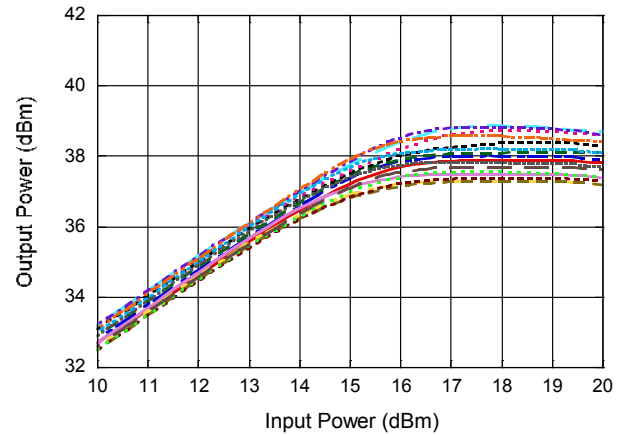
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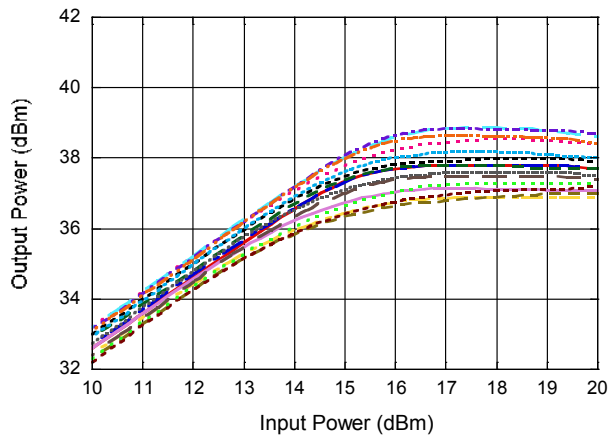
Load Ruggedness 2:1 vs. Input Power



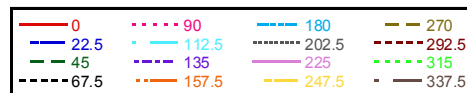
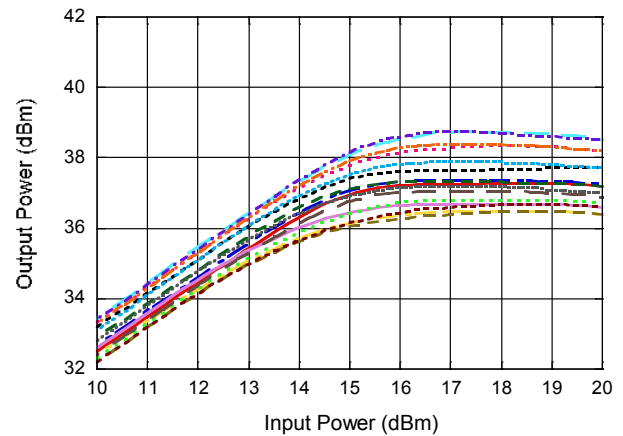
Load Ruggedness 3:1 vs. Input Power



Load Ruggedness 6:1 vs. Input Power



Load Ruggedness 9:1 vs. Input Power

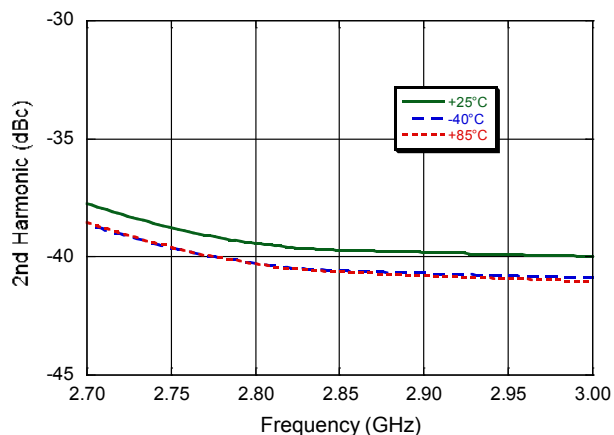


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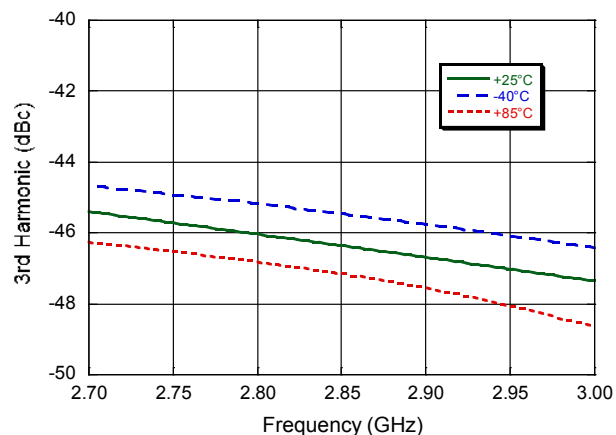
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Typical Performance Curves: $V_{DAx}=V_{DBx}=10$ V, $I_{DQ}=2.0$ A (80 μ s Pulse, 8% Duty Cycle)

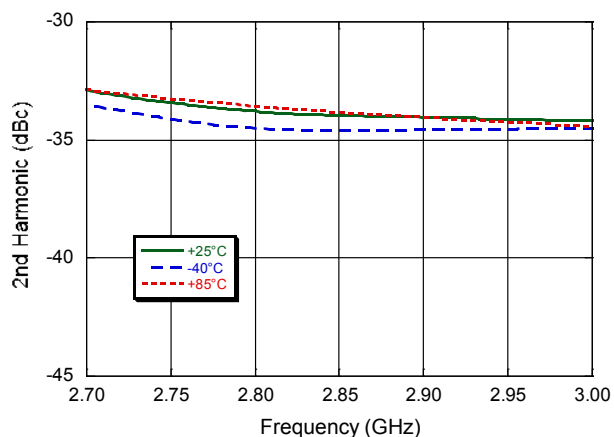
2nd Harmonic @ P1dB vs. Frequency



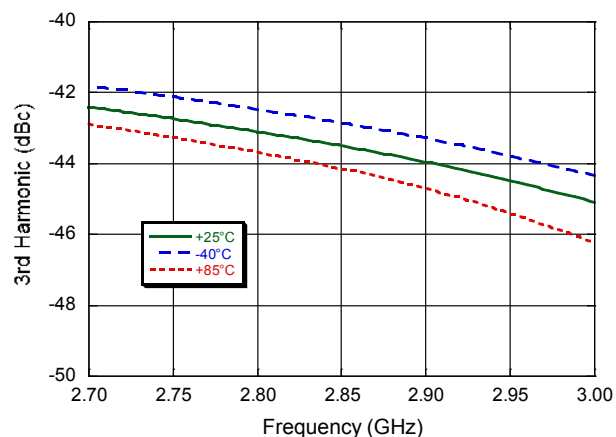
3rd Harmonic @ P1dB vs. Frequency



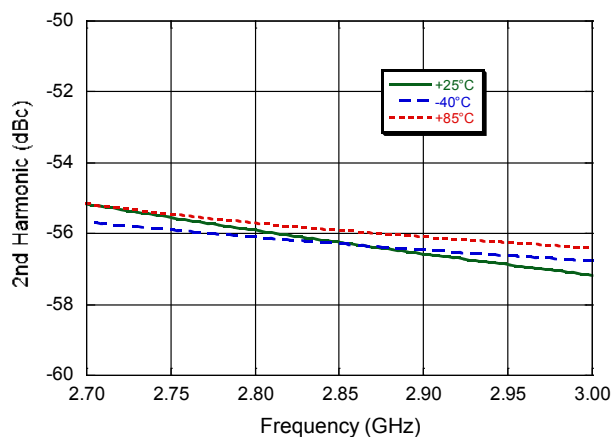
2nd Harmonic @ P3dB vs. Frequency



3rd Harmonic @ P3dB vs. Frequency



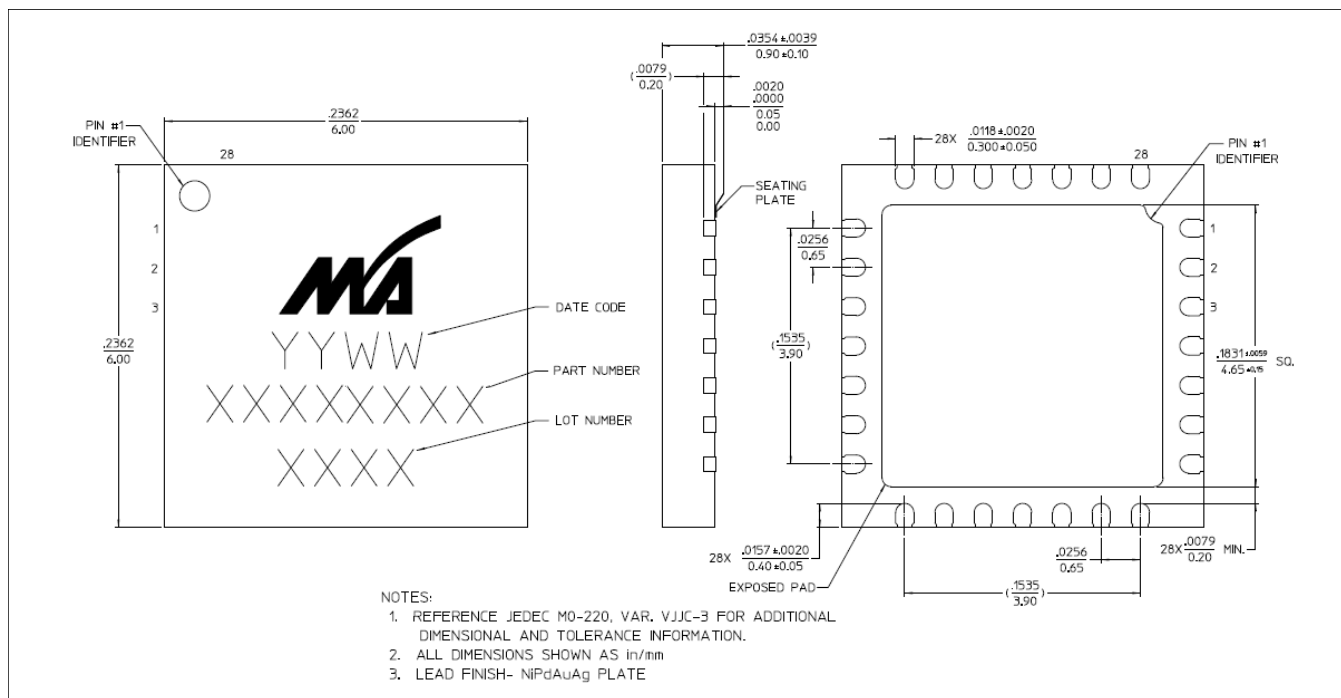
2nd Harmonic @ -10 dBm vs. Frequency



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Lead-Free 6 mm 28-Lead PQFN[†]



[†] Reference Application Note S2083 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is NiPdAuAg.

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Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331